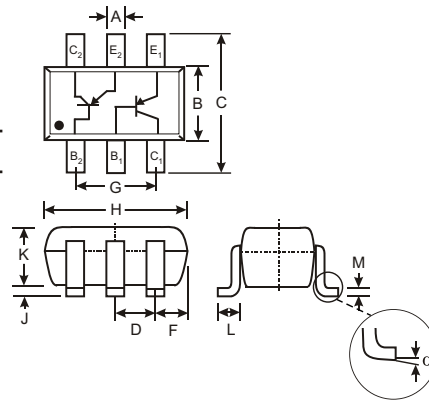


Features

- Epitaxial Planar Die Construction
- Intrinsically Matched PNP Pair (Note 1)
- Small Surface Mount Package
- 2% Matched Tolerance, h_{FE} , $V_{CE(SAT)}$, $V_{BE(SAT)}$
- 1% Matched Tolerance Available (Note 2)

Mechanical Data

- Case: SOT-363, Molded Plastic
- Case Material - UL Flammability Rating Classification 94V-0
- Moisture sensitivity: Level 1 per J-STD-020A
- Terminals: Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking (See Below): K4B
- Weight: 0.015 grams (approx.)
- Ordering & Date Code Information: See Below



| SOT-363 | | |
|----------------------|--------------|------|
| Dim | Min | Max |
| A | 0.10 | 0.30 |
| B | 1.15 | 1.35 |
| C | 2.00 | 2.20 |
| D | 0.65 Nominal | |
| F | 0.30 | 0.40 |
| H | 1.80 | 2.20 |
| J | — | 0.10 |
| K | 0.90 | 1.00 |
| L | 0.25 | 0.40 |
| M | 0.10 | 0.25 |
| α | 8° | |
| All Dimensions in mm | | |

Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

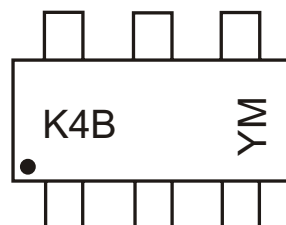
| Characteristic | Symbol | DMMT3906W | Unit |
|--|-----------------|-------------|---------------------------|
| Collector-Base Voltage | V_{CBO} | -40 | V |
| Collector-Emitter Voltage | V_{CEO} | -40 | V |
| Emitter-Base Voltage | V_{EBO} | -5.0 | V |
| Collector Current - Continuous | I_C | -200 | mA |
| Power Dissipation (Note 3) | P_d | 200 | mW |
| Thermal Resistance, Junction to Ambient (Note 3) | $R_{\theta JA}$ | 625 | $^\circ\text{C}/\text{W}$ |
| Operating and Storage and Temperature Range | T_j, T_{STG} | -55 to +150 | $^\circ\text{C}$ |

Ordering Information (Note 4)

| Device | Packaging | Shipping |
|-------------|-----------|------------------|
| DMMT3906W-7 | SOT-363 | 3000/Tape & Reel |

- Notes:
1. Built with adjacent die from a single wafer.
 2. Contact the Diodes, Inc. Sales department.
 3. Device mounted on FR5 PCB: 1.0 x 0.75 x 0.62 in.; pad layout as shown on suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.
 4. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



K4B = Product Type Marking Code
 YM = Date Code Marking
 Y = Year ex: N = 2002
 M = Month ex: 9 = September

Date Code Key

| Year | 2002 | 2003 | 2004 | 2005 | 2006 | 2007 | 2008 |
|------|------|------|------|------|------|------|------|
| Code | N | P | R | S | T | U | V |

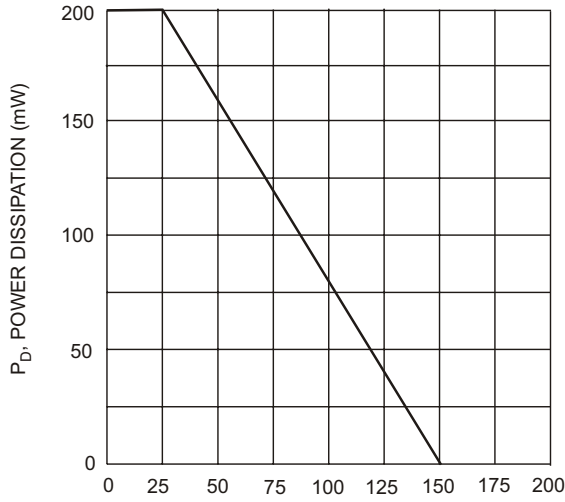
| Month | Jan | Feb | March | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
|-------|-----|-----|-------|-----|-----|-----|-----|-----|-----|-----|-----|-----|
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | O | N | D |

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

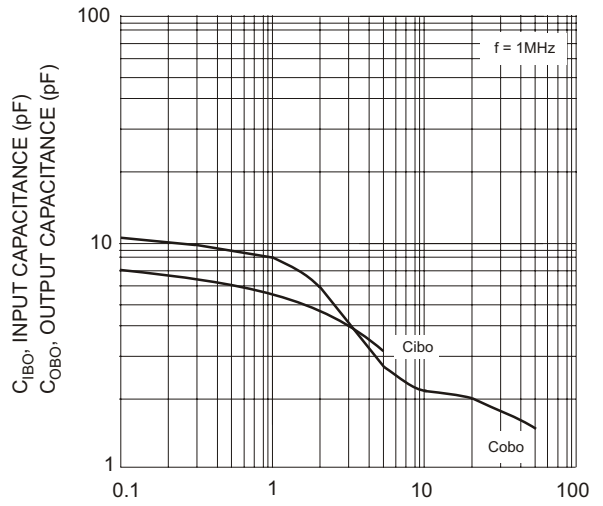
| Characteristic | Symbol | Min | Max | Unit | Test Condition |
|---|---------------|-----------------------------|-------------------------|------------------|--|
| OFF CHARACTERISTICS (Note 5) | | | | | |
| Collector-Base Breakdown Voltage | $V_{(BR)CBO}$ | -40 | — | V | $I_C = -10\mu\text{A}, I_E = 0$ |
| Collector-Emitter Breakdown Voltage | $V_{(BR)CEO}$ | -40 | — | V | $I_C = -1.0\text{mA}, I_B = 0$ |
| Emitter-Base Breakdown Voltage | $V_{(BR)EBO}$ | -5.0 | — | V | $I_E = -10\mu\text{A}, I_C = 0$ |
| Collector Cutoff Current | I_{CEX} | — | -50 | nA | $V_{CE} = -30\text{V}, V_{EB(OFF)} = -3.0\text{V}$ |
| Base Cutoff Current | I_{BL} | — | -50 | nA | $V_{CE} = -30\text{V}, V_{EB(OFF)} = -3.0\text{V}$ |
| ON CHARACTERISTICS (Note 5) | | | | | |
| DC Current Gain (Note 6) | h_{FE} | 60 80 100 60 30 | — — 300 — — | — | $I_C = -100\mu\text{A}, V_{CE} = -1.0\text{V}$ $I_C = -1.0\text{mA}, V_{CE} = -1.0\text{V}$ $I_C = -10\text{mA}, V_{CE} = -1.0\text{V}$ $I_C = -50\text{mA}, V_{CE} = -1.0\text{V}$ $I_C = -100\text{mA}, V_{CE} = -1.0\text{V}$ |
| Collector-Emitter Saturation Voltage (Note 6) | $V_{CE(SAT)}$ | — | -0.25 -0.40 | V | $I_C = -10\text{mA}, I_B = -1.0\text{mA}$ $I_C = -50\text{mA}, I_B = -5.0\text{mA}$ |
| Base-Emitter Saturation Voltage (Note 6) | $V_{BE(SAT)}$ | -0.65 — | -0.85 -0.95 | V | $I_C = -10\text{mA}, I_B = -1.0\text{mA}$ $I_C = -50\text{mA}, I_B = -5.0\text{mA}$ |
| SMALL SIGNAL CHARACTERISTICS | | | | | |
| Output Capacitance | C_{obo} | — | 4.5 | pF | $V_{CB} = -5.0\text{V}, f = 1.0\text{MHz}, I_E = 0$ |
| Input Capacitance | C_{ibo} | — | 10 | pF | $V_{EB} = -0.5\text{V}, f = 1.0\text{MHz}, I_C = 0$ |
| Input Impedance | h_{ie} | 2.0 | 12 | k Ω | $V_{CE} = 10\text{V}, I_C = 1.0\text{mA}, f = 1.0\text{kHz}$ |
| Voltage Feedback Ratio | h_{re} | 0.1 | 10 | $\times 10^{-4}$ | |
| Small Signal Current Gain | h_{fe} | 100 | 400 | — | |
| Output Admittance | h_{oe} | 3.0 | 60 | μS | |
| Current Gain-Bandwidth Product | f_T | 250 | — | MHz | $V_{CE} = -20\text{V}, I_C = -10\text{mA}, f = 100\text{MHz}$ |
| Noise Figure | NF | — | 4.0 | dB | $V_{CE} = -5.0\text{V}, I_C = -100\mu\text{A}, R_S = 1.0\text{k}\Omega, f = 1.0\text{kHz}$ |
| SWITCHING CHARACTERISTICS | | | | | |
| Delay Time | t_d | — | 35 | ns | $V_{CC} = -3.0\text{V}, I_C = -10\text{mA}, V_{BE(off)} = 0.5\text{V}, I_{B1} = -1.0\text{mA}$ |
| Rise Time | t_r | — | 35 | ns | |
| Storage Time | t_s | — | 225 | ns | $V_{CC} = -3.0\text{V}, I_C = -10\text{mA}, I_{B1} = I_{B2} = -1.0\text{mA}$ |
| Fall Time | t_f | — | 75 | ns | |

Notes: 5. Short duration test pulse used to minimize self-heating effect.

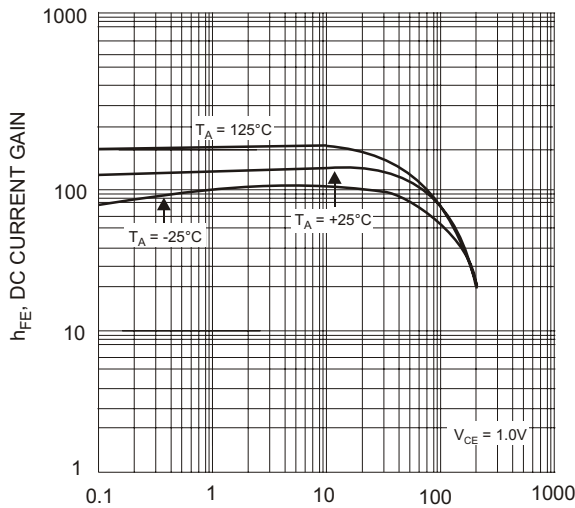
6. The DC current gain, h_{FE} , (matched at $I_C = -10\text{mA}$ and $V_{CE} = -1.0\text{V}$) Collector-Emitter Saturation Voltage, $V_{CE(sat)}$, and Base-Emitter Saturation Voltage, $V_{BE(sat)}$ are matched with typical matched tolerances of 1% and maximum of 2%.



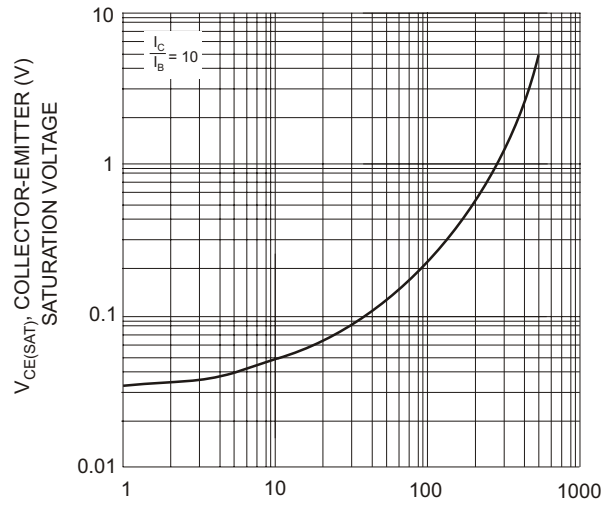
T_A, AMBIENT TEMPERATURE (°C)
Fig. 1, Max Power Dissipation vs Ambient Temperature



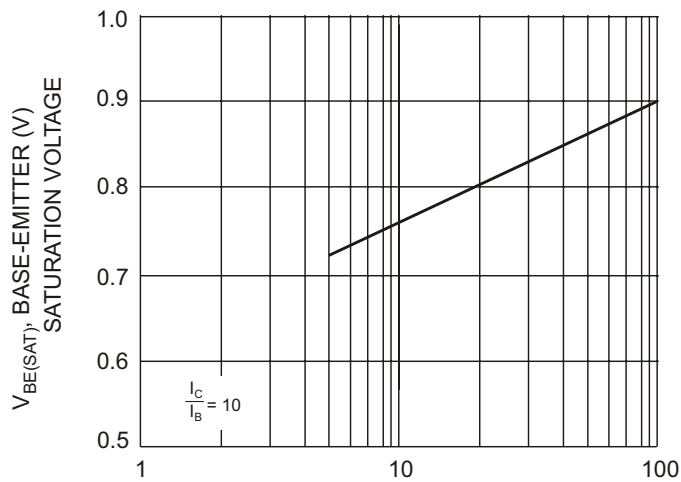
V_{CB}, COLLECTOR-BASE VOLTAGE (V)
Fig. 2, Input and Output Capacitance vs. Collector-Base Voltage



I_C, COLLECTOR CURRENT (mA)
Fig. 3, Typical DC Current Gain vs Collector Current



I_C, COLLECTOR CURRENT (mA)
Fig. 4, Typical Collector-Emitter Saturation Voltage vs. Collector Current



I_C, COLLECTOR CURRENT (mA)
Fig. 5, Typical Base-Emitter Saturation Voltage vs. Collector Current